

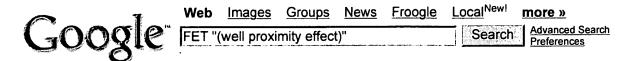
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[PDF] Chapter 14: Well Proximity Effect Model

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Experimental analysis[17] shows that **well proximity effect** is strong function of. distance of **FET** from mask edge, and electrical quantities influenced by it ...

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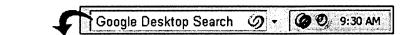
Gate direct tunneling. • Impact of halos on output resistance. • Well Proximity

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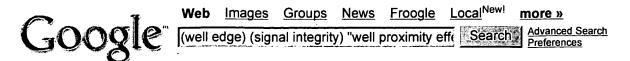
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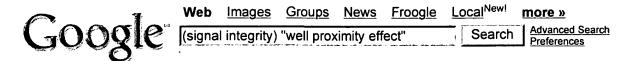
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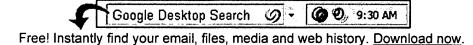
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[PDF] Let's Make It Work Design for Yield

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ebusiness.artisan.com/products/ papers/ACDC03_DesignForYield.pdf - Supplemental Result - Similar pages

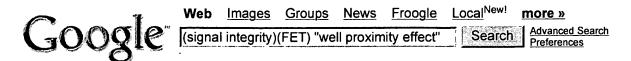


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IEE JNL	IEE Journal or Magazine	Select	A	Article Information				
IEEE CNF	IEEE Conference Proceeding		1.	Very low threshold oxide-confined 1.3 µm GaAs-based quantum dot lase Park, G.; Shchekin, O.B.; Huffaker, D.L.; Deppe, D.G.;				
IEE CNF	IEE Conference Proceeding			Lasers and Electro-Optics, 2000. (CLEO 2000). Conference on 7-12 May 2000 Page(s):349 - 350 Digital Object Identifier 10.1109/CLEO.2000.907100				
IEEE STD	IEEE Standard							
				AbstractPlus Full Text: PDF(168 KB) IEEE CNF				
		П		Reduced threshold ver Young, D.B.; Kapila, A.; Electronics Letters Volume 30, Issue 3, 3 F	Scott, J.W.; Malhot	tra, V.; Coldren, L.A.;		
				AbstractPlus Full Text:	PDF(256 KB) IEE	E JNL		
		П		Multi-quantum well Gal MOCVD Cheng, J.; Li, N.Y.; Hain: Device Research Confer 28-30 June 1999 Page(s Digital Object Identifier 1 AbstractPlus Full Text:	s, C.P.; Yang, K.; ence Digest, 1999):192 - 193 0.1109/DRC.1999.	57th Annual 806368	urrent den	

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1. CMOS Vt-control improvement through implant lateral scatter elimination

Polishchuk, I.; Mathur, N.; Sandstrom, C.; Manos, P.; Pohland, O.;

Semiconductor Manufacturing, 2005. ISSM 2005, IEEE International Symposic

13-15 Sept. 2005 Page(s):193 - 196

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